

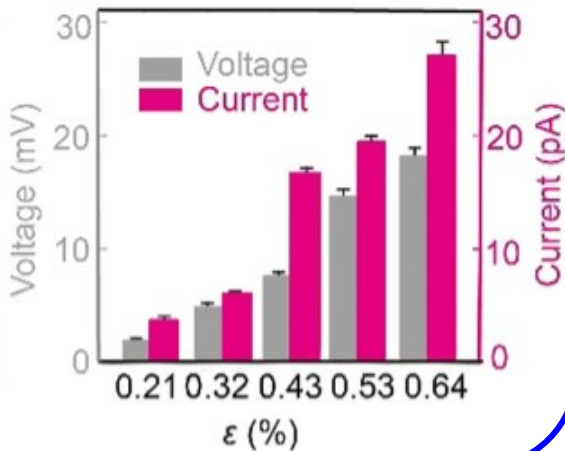
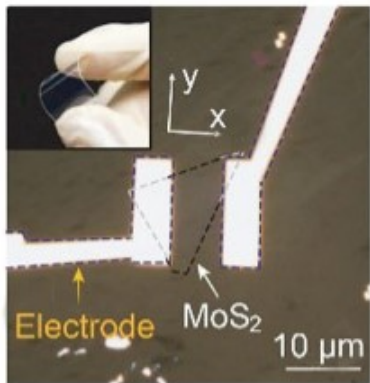
Solving Kohn-Sham Equations of Heterobilayer Systems Beyond 1000 Atoms: Twist Angle- dependent Piezoelectricity

PURDUE
UNIVERSITY

Han-Wei Hsiao, Namita Narendra, Tillmann Kubis
Purdue University, West Lafayette, IN, USA
Elmore Family School of Electrical and Computer Engineering

Applications of 2D piezoelectric materials:

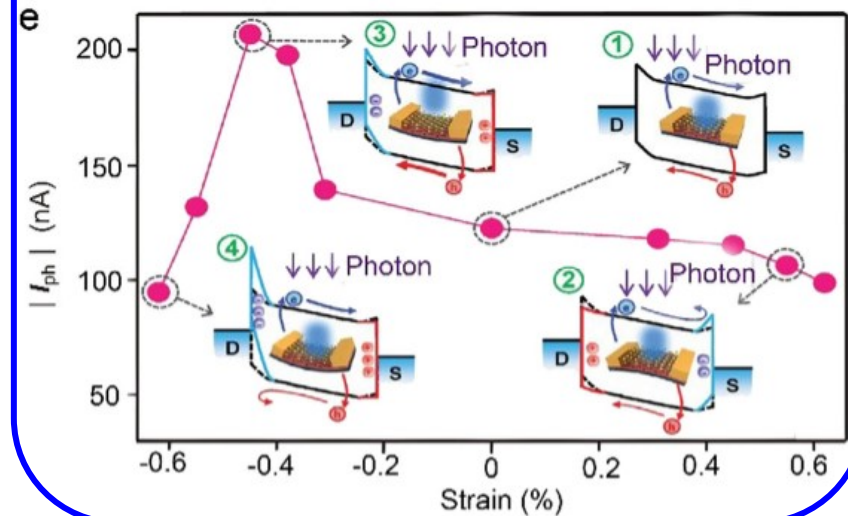
Energy harvesting (nanogenerator)



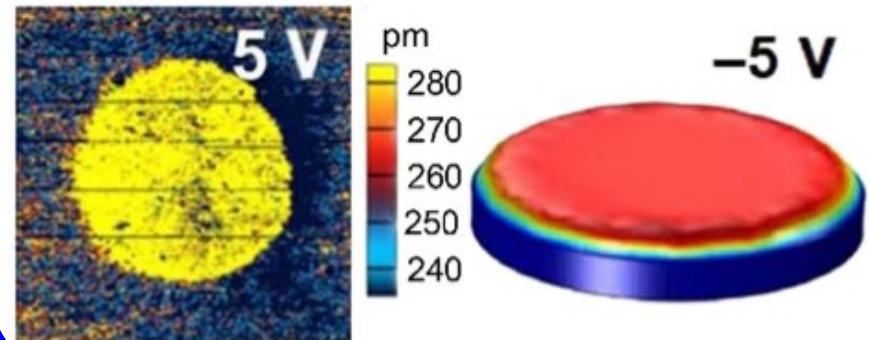
Stacking 2D materials allows more functionalization possibilities

Twist angle offers a new degree of freedom!

Piezophototronic

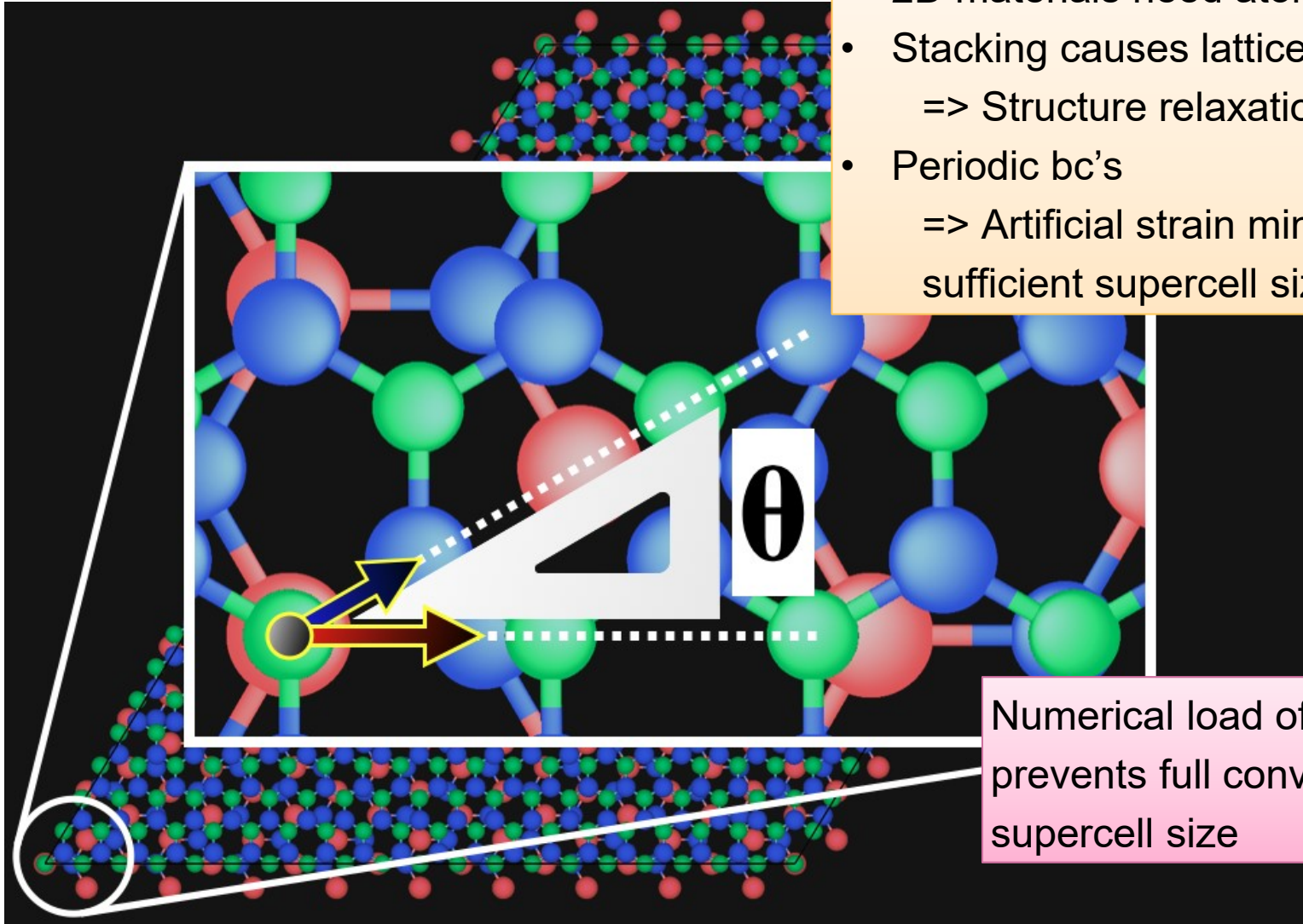


Actuator



Motivation - Modeling Challenge

- 2D materials need atomic resolution
- Stacking causes lattice mismatch
=> Structure relaxation
- Periodic bc's
=> Artificial strain minimized with sufficient supercell size



Numerical load of DFT typically prevents full convergence w.r.t supercell size

The total energy given in DFT (Kohn-Sham method):

$$E = T_o[\rho] + \int V_{ext} \rho(\vec{r}) d\vec{r} + \frac{1}{2} \int \frac{\rho(\vec{r}) \rho(\vec{r}')}{|\vec{r}' - \vec{r}|} d\vec{r} d\vec{r}' + E_{xc}[\rho]$$

Repulsive Potentials

E_{kinetic}
non interacting

E_{ne}

E_{coulomb} E_{ee}

E_{xc} exchange-correlation

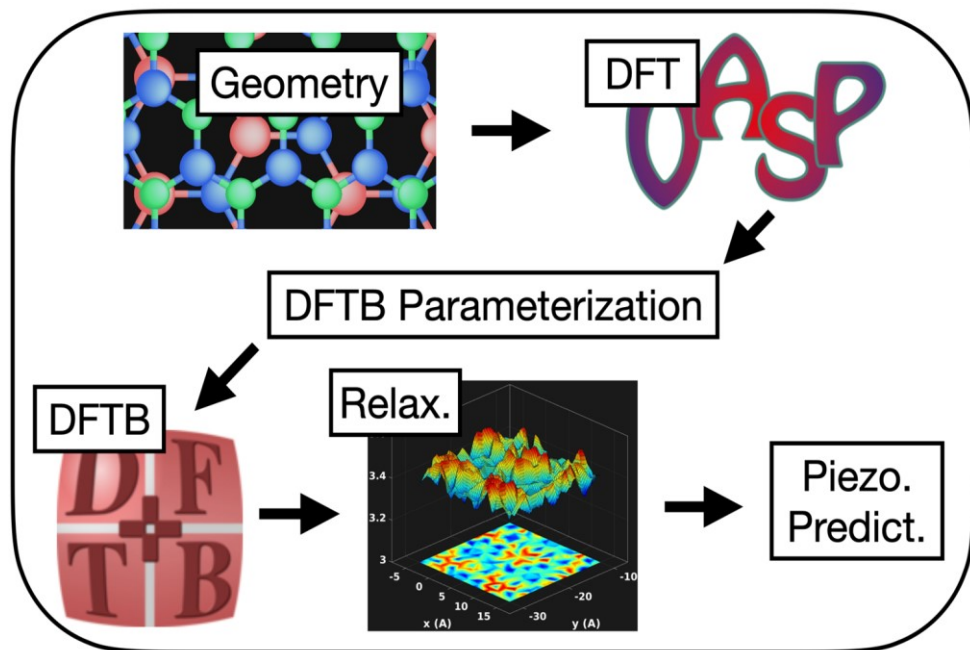
DFTB Energy

(Electronic Parameters: On-site energies, compression radii, etc.)

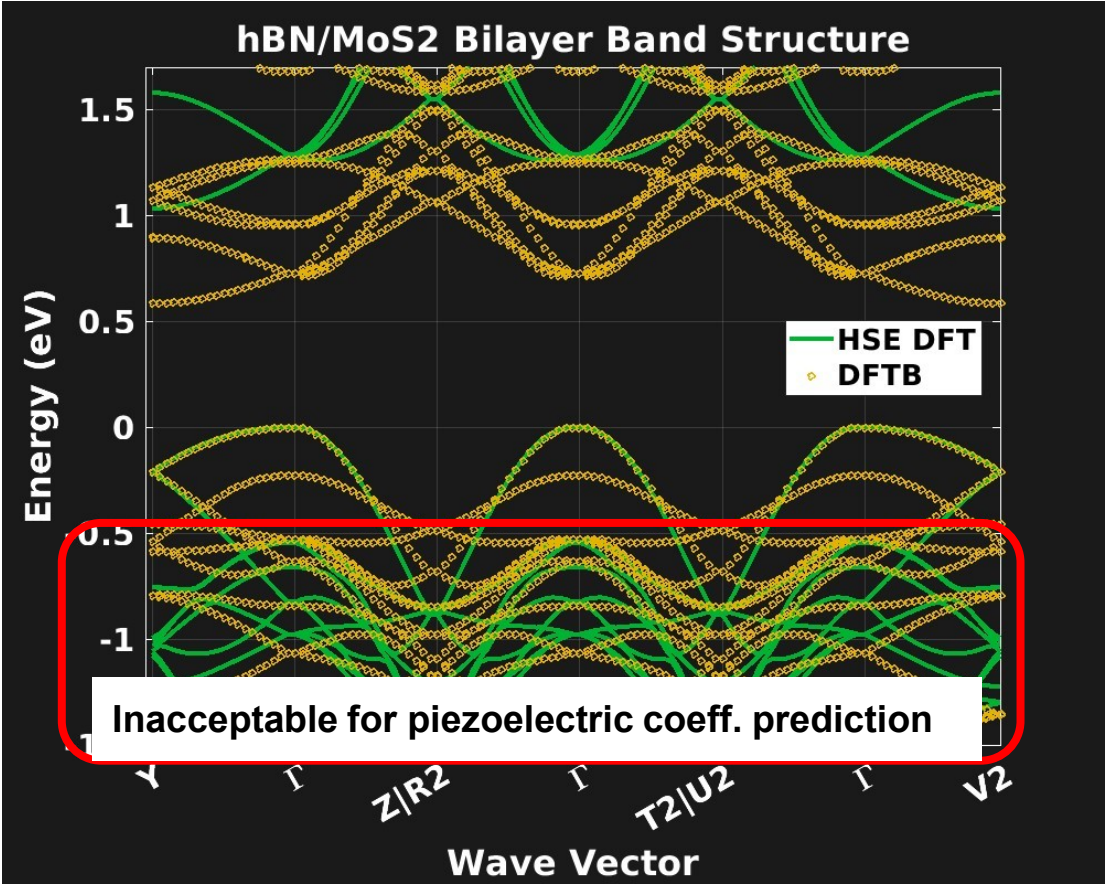
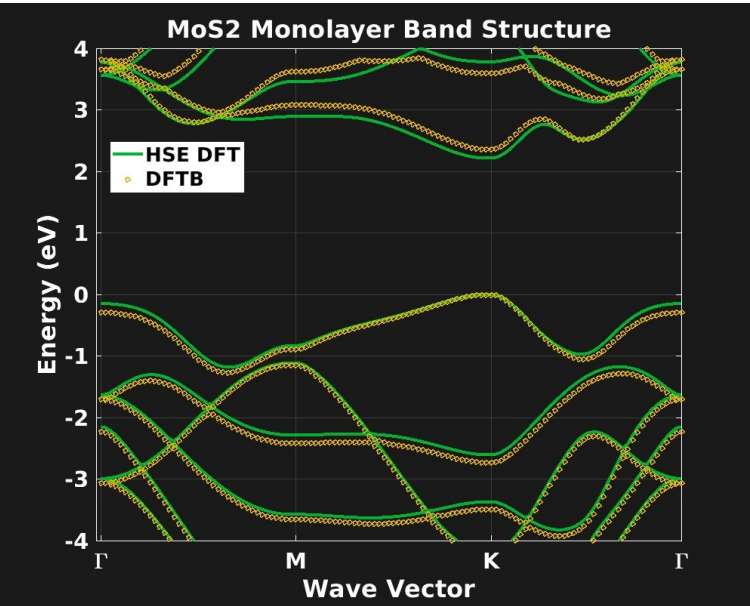
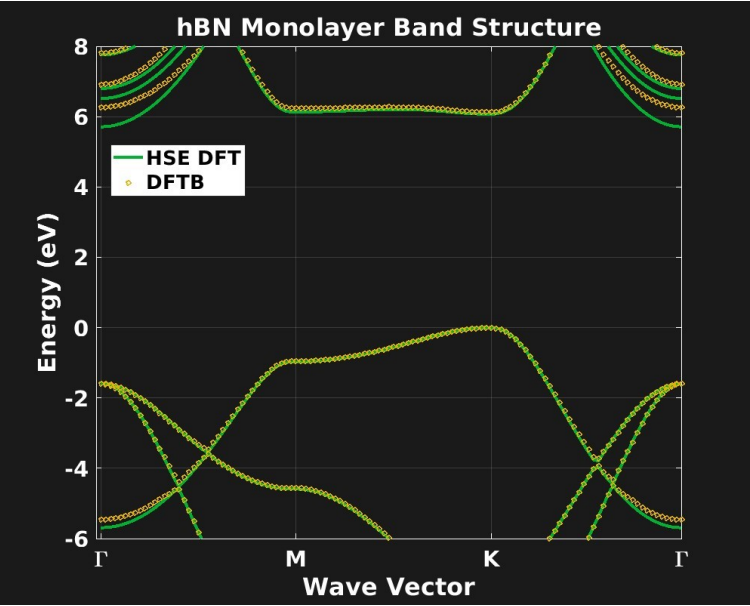
This method:

- Structure relaxation while solving Kohn-Sham equations of sufficiently large structures
- DFTB parameters fit to reproduce DFT HSE06 results

Method flow diagram

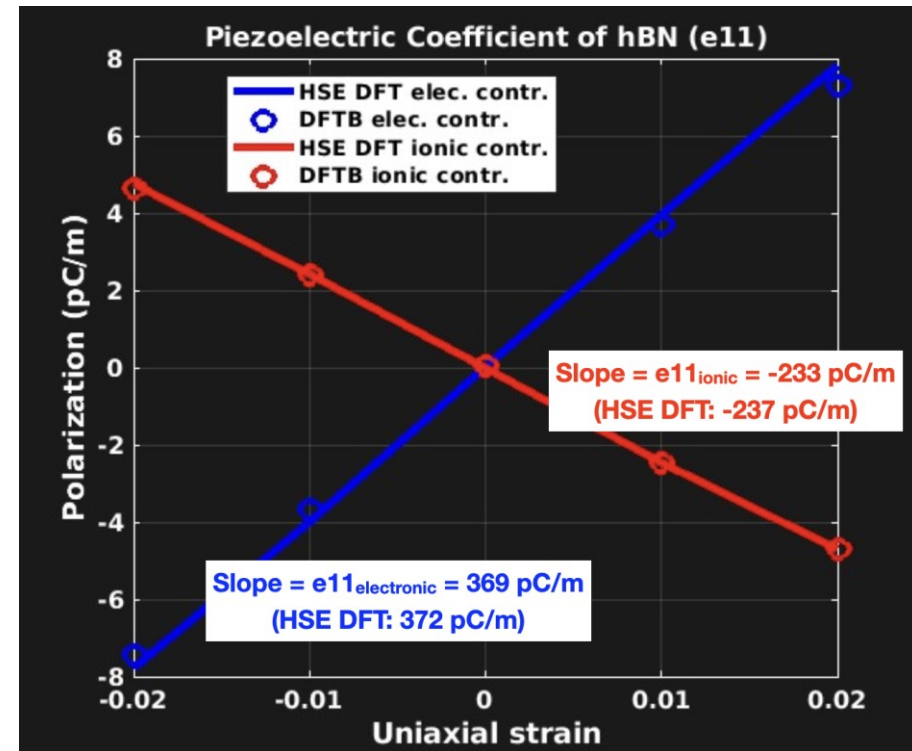
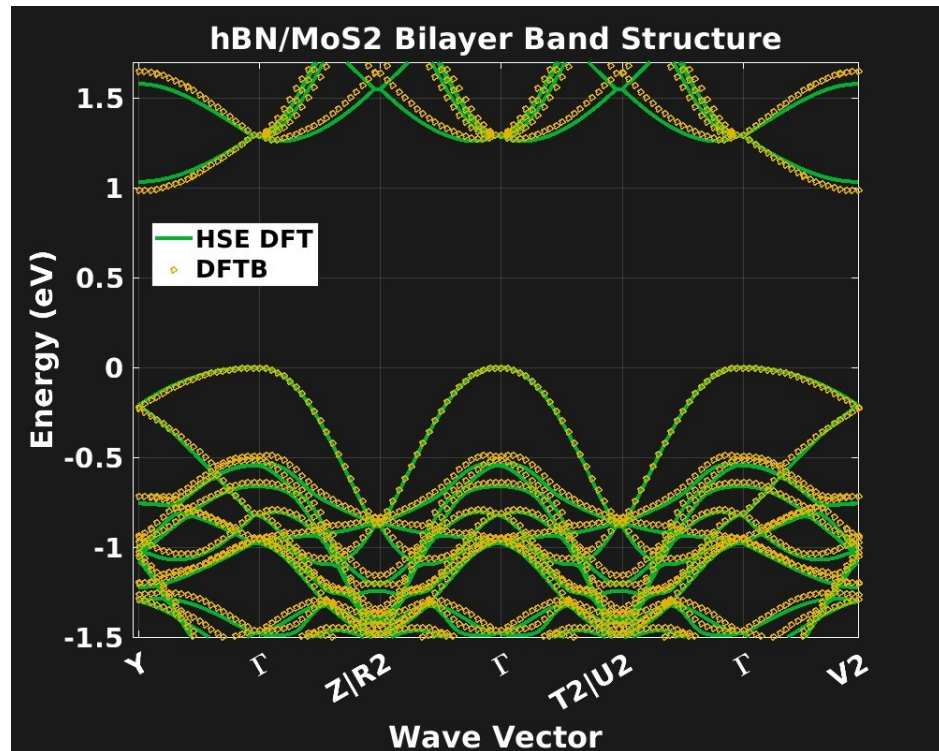


Results: Parameter Transferability



- Parameters are not transferable between monolayer and bilayer structures
- All parameters are fitted simultaneously for each system respectively

Results: Parameterization



DFTB vs. HSE06 DFT:

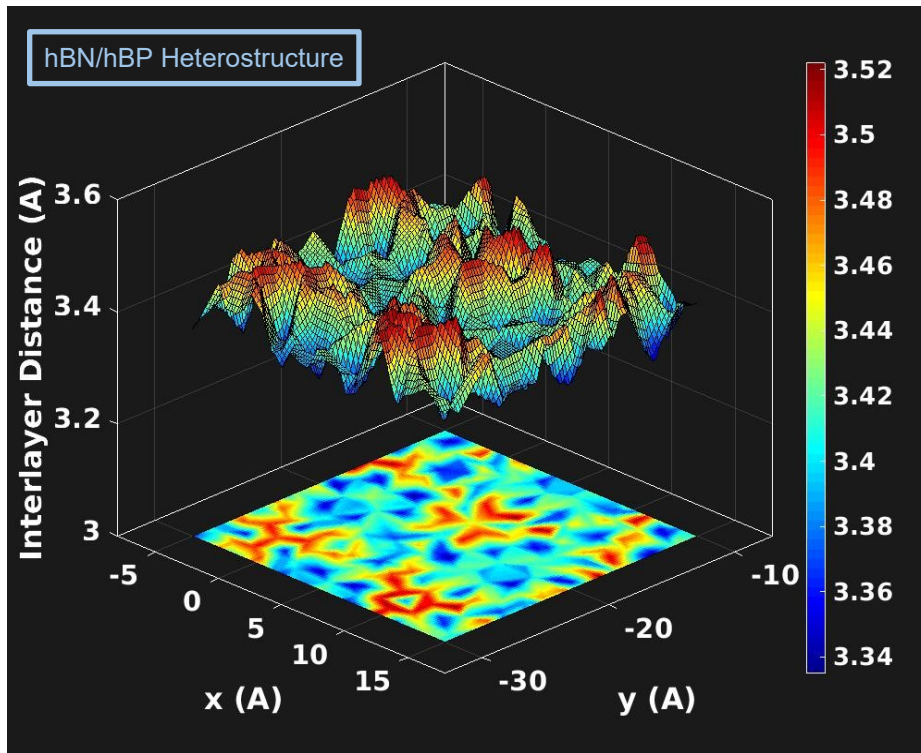
- ✓ DFTB parameters are transferable between monolayer and bilayer structures
- ✓ Deep lying valence bands reproduced
- ✓ Piezoelectric coefficients agree with DFT calculations in small systems

HSE DFT: elec. contr. $e_{11} = 372$ pC/m, ionic contr. -237 pC/m

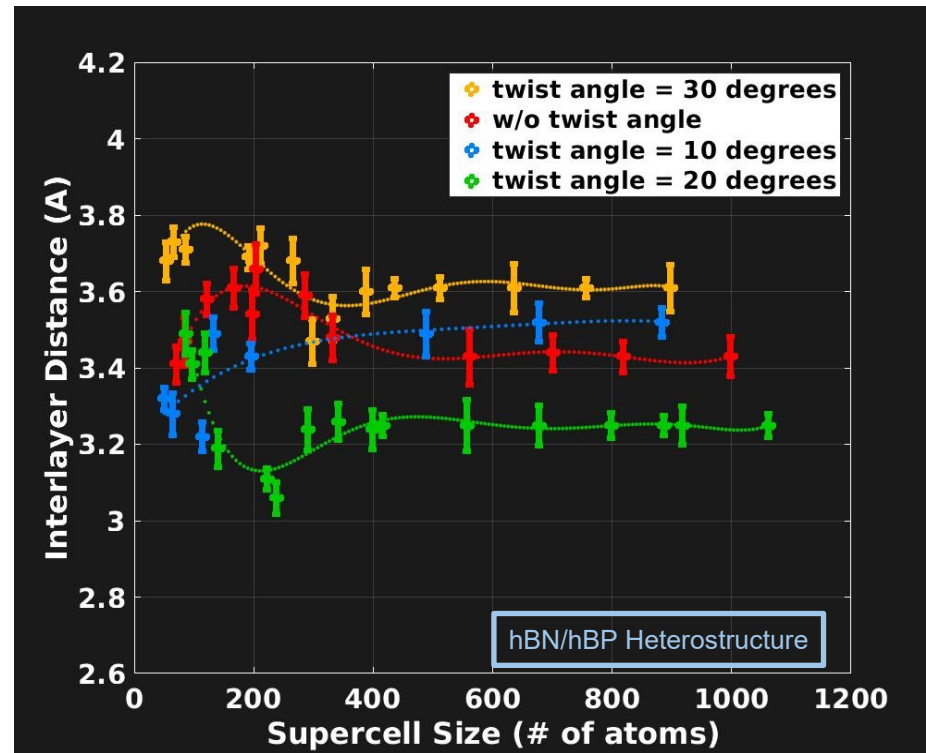
DFTB: elec. contr. $e_{11} = 369$ pC/m, ionic contr. -233 pC/m

Result: Convergence vs. Supercell Size

Corrugation Field @ $\theta = 10$ degrees



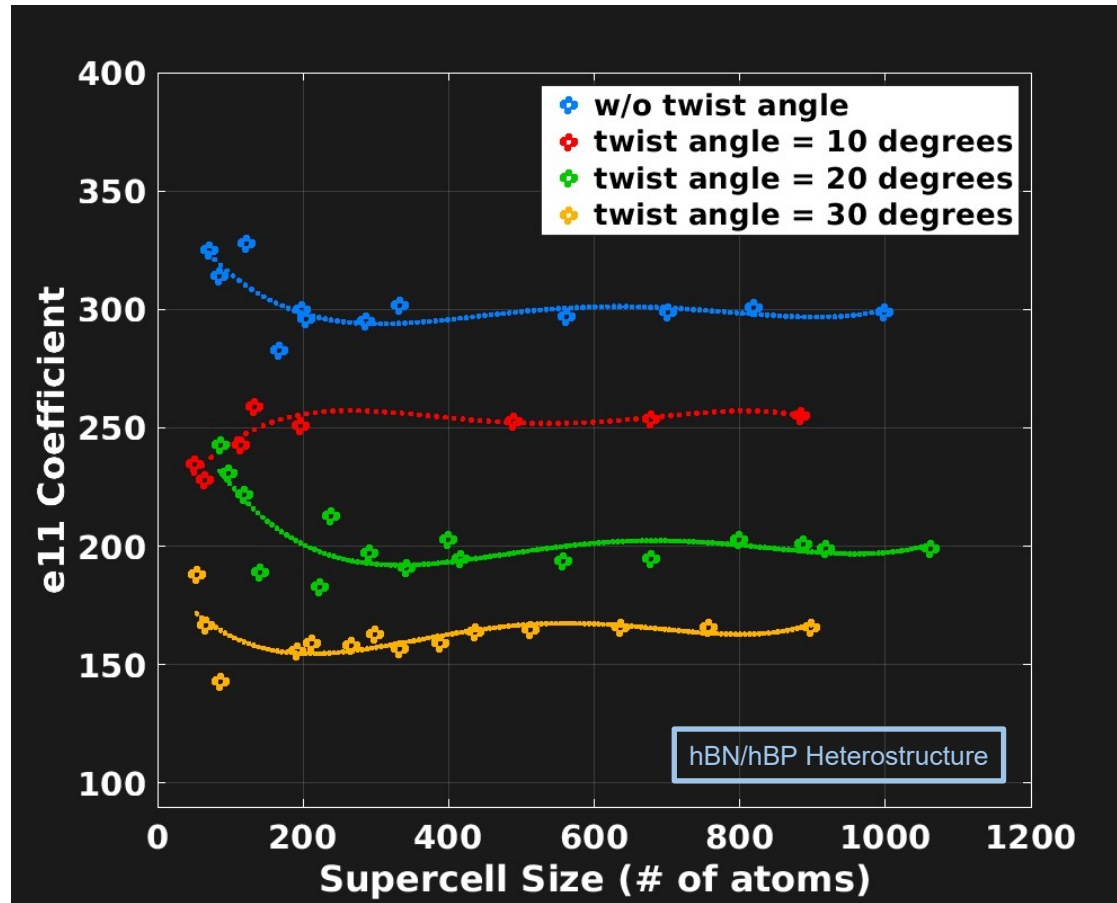
Averaged Interlayer Distance vs. Cell Size



- ✓ Artificial boundary effects are avoided with sufficient supercell sizes
- ✓ Supercells containing ~1000 atoms are possible with DFTB
- ✓ Typical minimum ~600 atoms (angle dependent)

Result: Convergence vs. Supercell Size

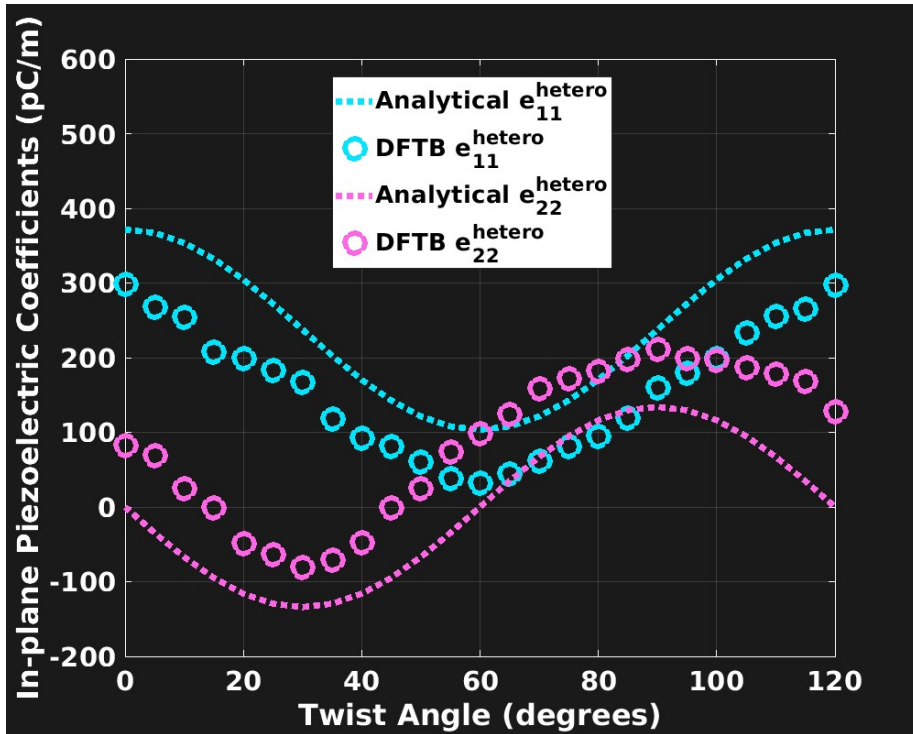
In-plane Piezoelectric Coefficient



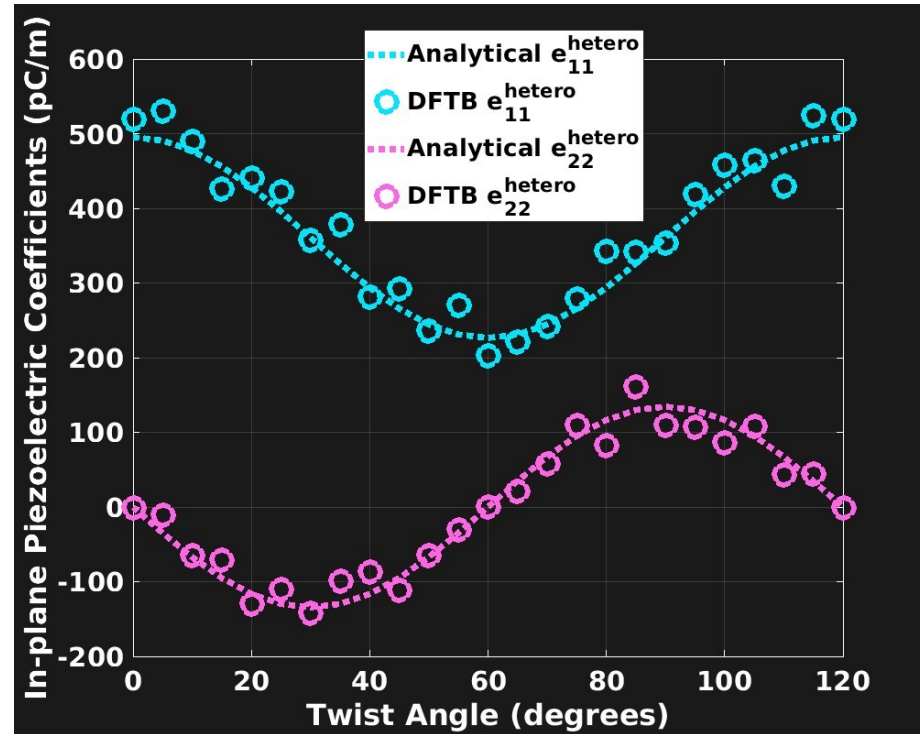
✓ Piezoelectric coefficient converges with supercell size

Result: In-plane Piezoelectric Coefficients

hBN/hBP Heterostructure



hBN/MoS2 Heterostructure



Analytical Model (perfect sym.)

$$e_{11}^{\text{Hetero}} = e_{11}^{\text{hBN}} \cos(3\theta) + e_{11}^{\text{MoS2/hBP}}$$

$$e_{22}^{\text{Hetero}} = -e_{11}^{\text{hBN}} \sin(3\theta) + e_{22}^{\text{MoS2/hBP}}$$

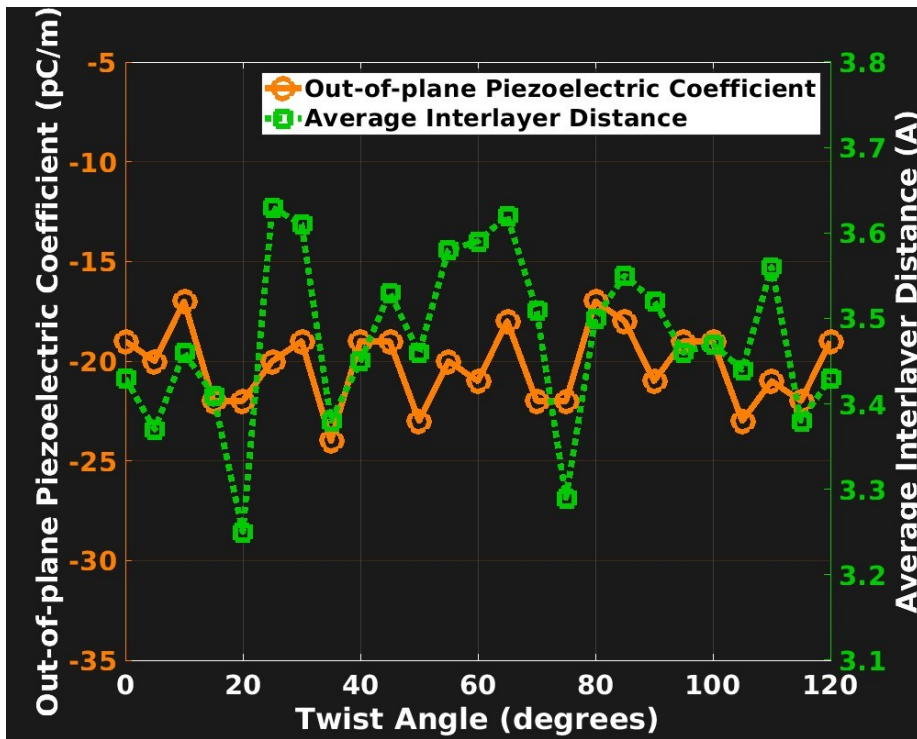
- Material symmetry (here: 120-degree) reproduced
- Deviation from symmetry due to interlayer charge transfer, corrugation, twist-angle dependence, etc.

Relevant for device design: In-plane piezoelectric coefficients are tunable

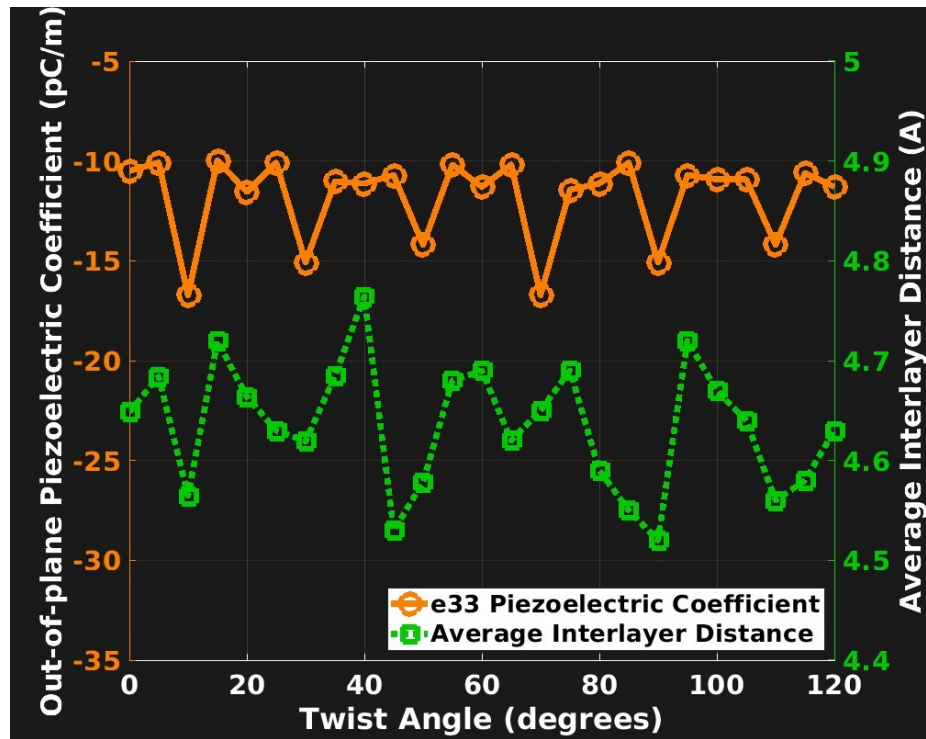
Result: Out-of-plane Piezoelectricity

Out of plane response due to broken inversion symmetry along z expected

hBN/hBP Heterostructure



hBN/MoS2 Heterostructure



Finite out-of-plane piezoelectricity confirmed

This talk:

- ✓ Introduction of method for reliable and efficient piezoelectricity prediction of 2D heterobilayer systems
- ✓ The method guarantees convergence of results vs. system size

Take home message:

- Large enough supercell is required for piezoelectricity prediction
- In-plane piezoelectric coefficients are tunable
- Finite out-of-plane piezoelectric response confirmed

Thank you!